

#### 30V P-Channel Enhancement Mode MOSFET

Voltage -30 V Current -4.6A

#### **Features**

- RDS(ON), VGS@-10V, ID@-4.6A<72mΩ
- RDS(ON) , VGS@-4.5V, ID@-3.0A<96mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

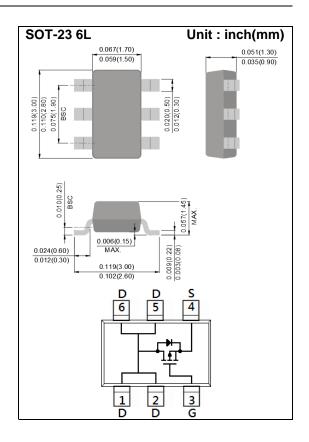
#### **Mechanical Data**

• Case: SOT-23 6L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0005 ounces, 0.014 grams

Marking: S05



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-30	V
Gate-Source Voltage		V <sub>G</sub> s	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	-4.6	Α
Pulsed Drain Current		I <sub>DM</sub>	-18.4	Α
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	2	W
	Derate above 25°C		16	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal Resistance				
- Junction to Ambient <sup>(Note 3)</sup>		R <sub>θJA</sub>	62.5	°C/W



## **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-1	-1.38	-2.1	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-4.6A	-	61	72	mΩ	
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-3.0A	-	78	96		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	-	-0.01	-1	uA	
Gate-Source Leakage Current	Igss	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA	
Dynamic							
Total Gate Charge	$Q_g$		-	5.2	-	nC	
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =-15V, I <sub>D</sub> =-4.6A,	-	1.3	-		
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =-10V <sup>(Note 1,2)</sup>	-	1.9	-		
Input Capacitance	Ciss		-	417	-	pF	
Output Capacitance	Coss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V,	-	50	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	36	-		
Switching							
Turn-On Delay Time	td <sub>(on)</sub>	151/ 1 404	-	3.5	-		
Turn-On Rise Time	tr	$V_{DD}$ =-15V, $I_{D}$ =-4.6A, $V_{GS}$ =-10V, $R_{G}$ =6 $\Omega^{(Note 1,2)}$	-	34	-	ns	
Turn-Off Delay Time	td <sub>(off)</sub>		-	120	-		
Turn-Off Fall Time	tf	KG=012(1000 1,2)	-	71	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	Is		-	_	-2.0	А	
Diode Forward Current							
Diode Forward Voltage	$V_{\text{SD}}$	Is=-1.0A, V <sub>GS</sub> =0V	-	-0.74	-1.2	V	

#### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%</a>.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.



#### **TYPICAL CHARACTERISTIC CURVES**

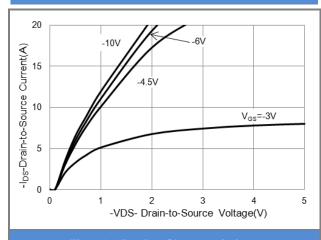
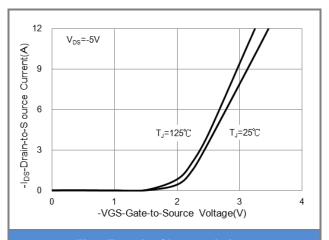


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

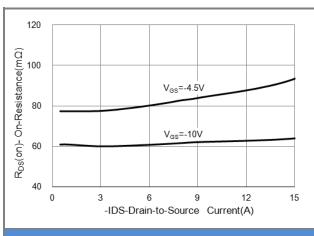


Fig.3 On-Resistance vs. Drain Current

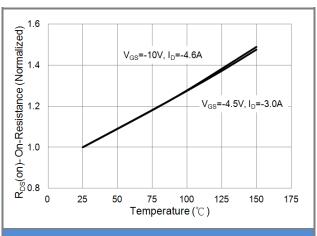
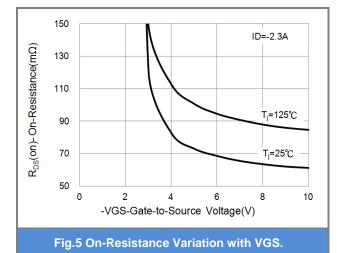


Fig.4 On-Resistance vs. Junction temperature



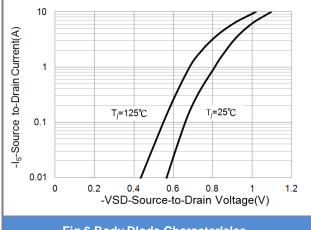


Fig.6 Body Dlode CharacterIslcs



#### **TYPICAL CHARACTERISTIC CURVES**

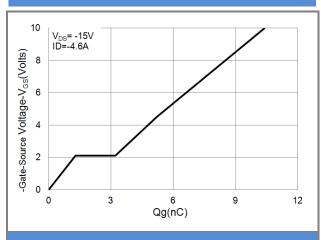


Fig.7 Gate-Charge Characteristics

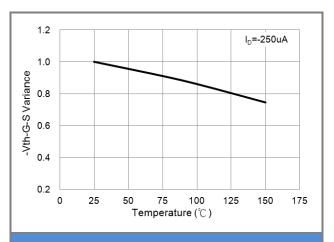


Fig.8 Threshold Voltage Variation with Temperature.

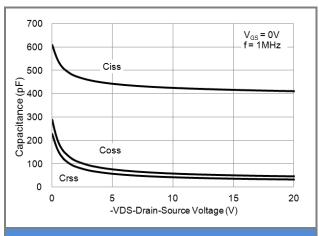


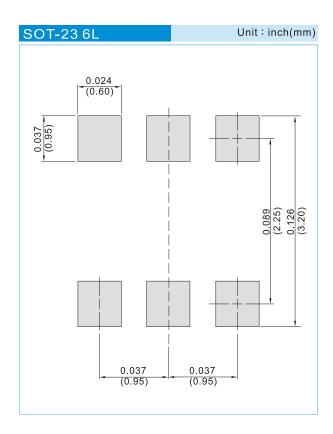
Fig.9 Capacitance vs. Drain-Source Voltage.



# **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking	
PJS6405	SOT-23 6L	3K pcs / 7" reel	S05	
PJS6405	SOT-23 6L	10K pcs / 13" reel	S05	

## **Mounting Pad Layout**





#### Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are
  responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no
  representation or warranty that such applications will be suitable for the specified use without further testing or
  modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.